



HIGH VOLTAGE, MEDIUM POWER, NPN TRANSISTOR IN A HERMETICALLY SEALED **CERAMIC SURFACE MOUNT PACKAGE** FOR HIGH RELIABILITY APPLICATIONS

MECHANICAL DATA Dimensions in mm (inches)

2.03 ± 0.20 (0.08 ± 0.008)

LCC3 PACKAGE **Underside View**

PAD 1 - Collector PAD 3 - Emitter PAD 2 - N/C PAD 4 - Base

FEATURES

- SILICON PLANAR EPITAXIAL NPN TRANSISTOR
- HERMETIC CERAMIC SURFACE MOUNT **PACKAGE**
- CECC SCREENING OPTIONS
- SPACE QUALITY LEVELS OPTIONS
- HIGH VOLTAGE

APPLICATIONS:

Hermetically sealed surface mount version of the popular 2N3439 & 2N3440 for high reliability / space applications requiring small size and low weight devices.

ABSOLUTE	MAXIMUM RATINGS (T _{case} = 25°C unless otherwise stated)	2N3439	2N3440
V_{CBO}	Collector – Base Voltage	450V	300V
V_{CEO}	Collector – Emitter Voltage (I _B = 0)	350V	250V
V_{EBO}	Emitter – Base Voltage (I _B = 0)	7V	
$I_{\mathbb{C}}$	Collector Current	500mA	
P_{D}	Total Device Dissipation	350mW	
P_{D}	Derate above 50°C	2.0mW / °C	
R_{ja}	Thermal Resistance Junction to Ambient	350°C/W	
T _{stg}	Storage Temperature	−55 to 200°C	

Semelab PIc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

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2N3439CSM4 2N3440CSM4

ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

Parameter		Test Conditions	Min.	Тур.	Max.	Unit
V _{CEO(sus)*}	Collector – Emitter Sustaining Voltage	I _C = 50mA 2N3439	350			V
	$(I_{B}=0)$	I _C = 50mA 2N3440	250			, v
I _{CEO}	Collector Cut-off Current	V _{CE} = 300V 2N3439			20	μА
	$(I_{B}=0)$	V _{CE} = 200V 2N3440			50	
I _{CEX}	Collector Cut-off Current	V _{CE} = 450V 2N3439			500	μΑ
	$(V_{BE} = -1.5V)$	V _{CE} = 300V 2N3440			500	
I _{CBO}	Collector – Base Cut-off Current	V _{CB} = 350V 2N3439			20	
	$(I_E = 0)$	V _{CB} = 250V 2N3440			20	μA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 6V			20	μΑ
V _{CE(sat)*}	Collector - Emitter Saturation Voltage	$I_C = 50 \text{mA}$ $I_B = 4 \text{mA}$			0.5	V
V _{BE(sat)*}	Base – Emitter Saturation Voltage	$I_C = 50 \text{mA}$ $I_B = 4 \text{mA}$			1.3	V
h _{FE*}	DC Current Gain	I _C = 20mA	40		160	_
		V _{CE} = 10V	40			
		I _C = 2mA 2N3439 only	30			
		V _{CE} = 10V	30			

^{*} Pulse test $t_p=300\mu s$, $\delta \leq 2\%$

DYNAMIC CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

Parameter		Test Conditions			Min.	Тур.	Max.	Unit
f _T	Transition Frequency	I _C = 10mA	V _{CE} = 10V	f = 5MHz	15			MHz
C _{ob}	Output Capacitance	V _{CB} = 10V		f = 1MHz			10	pF
h _{fe}	Small Signal Current Gain	$I_C = 5mA$	V _{CE} = 10V	f = 1kHz	25			_

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